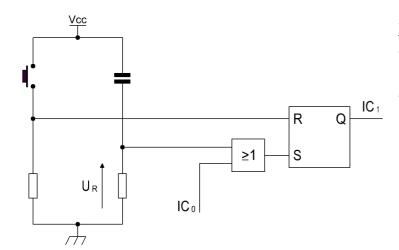
T.D. 4

Émission série du contenu d'une ROM

PARTIE 1: Initialisation et commande



Indications

- On suppose que le bouton poussoir n'est pas pressé lors de la mise sous tension.
- La tension de seuil des entrées de la porte OU est V_{cc}/2.

- À la mise sous tension, dessinez l'évolution de la tension U_R aux bornes de la résistance et donnez le niveau logique considéré par la porte OU.
- 2. Exprimez S en fonction de IC_0 , en régime transitoire et permanent.
- 3. Si IC_0 est au niveau bas à l'allumage, à quelle valeur est initialisée la sortie IC_1 ?
- 4. Comment faire passer la sortie IC_1 à 0 quand elle est à 1 (avec R = 0 et S = 0)?
- 5. Comment faire passer la sortie IC_1 à 1 quand elle est à 0 (avec R = 0 et S = 0)?

PARTIE 2: Les compteurs

On désire réaliser un compteur C_1 , sur 11 bits $(Q_{10} - Q_0)$, et un compteur C_2 , sur 4 bits modulo 10 $(Q_3' - Q_0')$. Pour C_1 , on dispose de plusieurs **74HCT193**. Pour C_2 , on dispose d'un **74HCT192**. On appelle respectivement CK_1 et CK_2 les entrées d'horloge de C_1 et de C_2 .

- 6. Combien de **74HCT193** doit-on utiliser pour réaliser C₁ ?
- 7. À l'aide de la <u>documentation technique du 74HCT193</u>, déterminez les autres noms donnés aux entrées C₃, 2+, 1- et R, puis détaillez le fonctionnement de toutes les entrées-sorties du 74HCT193.
- 8. Donnez un schéma de câblage pour C₁ en supposant qu'il compte en boucle.
- 9. À l'aide du montage de la partie 1 et de la question précédente, remplissez en partie le <u>document</u> réponse afin de réaliser les conditions suivantes :
 - Les sorties de C₁ doivent être initialisées à 0 lors de la mise sous tension.
 - C₁ doit commencer à compter après un appui sur le bouton poussoir.
 - C₁ doit s'arrêter de compter et garder toutes ses sorties à 0 après avoir atteint sa valeur maximale.
- 10. Câblez le **74HCT192** sur le <u>document réponse</u> sachant que C₂ compte uniquement lorsque C₁ compte et qu'il positionne un 0 sur toutes ses sorties dans le cas contraire. Le **74HCT192** est la version modulo 10 du **74HCT193**.

T.D. 4

PARTIE 3 : Lecture de la ROM

On désire lire toutes les adresses successives d'une ROM de type M2716 après un appui sur le bouton poussoir. On utilisera pour cela le compteur C_1 .

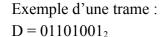
11. En vous aidant de la <u>documentation technique d'une **M2716**</u>, câblez chaque entrée de la ROM sur le <u>document réponse</u>.

PARTIE 4 : Émission série

On désire transférer le contenu d'une ROM de type M2716 via une liaison série RS-232.

Structure d'une trame :

- Un bit de start égal à 0.
- Huit bits de données.
- Un bit de *stop* égal à 1 (servant aussi de bit de repos).
- Une vitesse de transmission de 9600 bauds.





La conversion parallèle-série se fera à l'aide du multiplexeur **MM74C150** (*cf.* documentation technique ci-jointe).

- 12. Que faut-il ajouter en sortie du multiplexeur?
- 13. Combien d'entrées E_n du multiplexeur seront utilisées ?
- 14. Lorsqu'il n'y a pas d'émission, les entrées **ABCD** du multiplexeur sont nulles. Câblez les entrées E_n sur le <u>document réponse</u> afin d'obtenir la trame voulue.
- 15. Ce sont les sorties de C_2 qui vont servir à piloter le multiplexeur. Terminez le câblage des entrées du multiplexeur.
- 16. Quelle fréquence doit être présente sur CK₂?

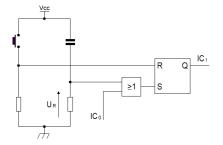
L'octet de l'adresse de la ROM doit rester présent en entrée du multiplexeur durant la totalité du transfert de tous ses bits. Une fois transféré, on doit passer à l'octet suivant.

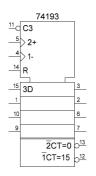
- 17. À quoi faut-il relier CK_1 ?
- 18. Combien de temps durera le transfert de toute la mémoire ?

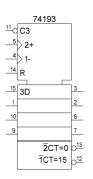
Afin d'économiser le nombre de composants, toutes les portes et les bascules de ce montage seront réalisées à l'aide de portes NON-OU.

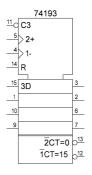
19. Donnez le nouveau schéma de câblage.

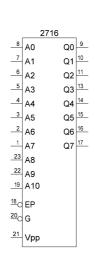
T.D. 4 2/12

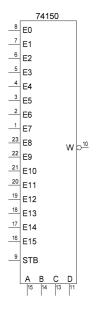


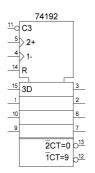














M2716

NMOS 16K (2K x 8) UV EPROM

- 2048 x 8 ORGANIZATION
- 525mW Max ACTIVE POWER, 132mW Max STANDBY POWER
- ACCESS TIME:
 - M2716-1 is 350ns
 - M2716 is 450ns
- SINGLE 5V SUPPLY VOLTAGE
- STATIC-NO CLOCKS REQUIRED
- INPUTS and OUTPUTS TTL COMPATIBLE DURING BOTH READ and PROGRAM MODES
- THREE-STATE OUTPUT with TIED-OR-CAPABILITY
- EXTENDED TEMPERATURE RANGE
- PROGRAMMING VOLTAGE: 25V

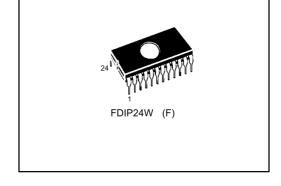


Figure 1. Logic Diagram

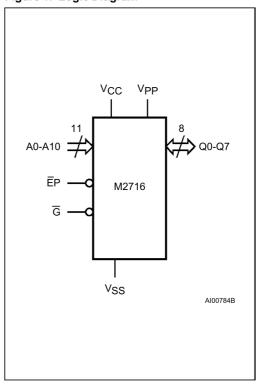
DESCRIPTION

The M2716 is a 16,384 bit UV erasable and electrically programmable memory EPROM, ideally suited for applications where fast turn around and pattern experimentation are important requirements.

The M2716 is housed in a 24 pin Window Ceramic Frit-Seal Dual-in-Line package. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written to the device by following the programming procedure.

Table 1. Signal Names

A0 - A10	Address Inputs							
Q0 - Q7	Data Outputs							
E P	Chip Enable / Program							
G	Output Enable							
V _{PP}	Program Supply							
Vcc	Supply Voltage							
V _{SS}	Ground							



July 1994 1/9

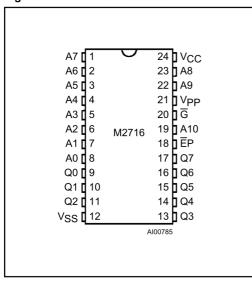
M2716

Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit	
T _A	Ambient Operating Temperature	0 to 70 –40 to 85	°C	
T _{BIAS}	Temperature Under Bias	grade 1 grade 6	–10 to 80 –50 to 95	°C
T _{STG}	Storage Temperature		-65 to 125	°C
V _{CC}	Supply Voltage		–0.3 to 6	V
V _{IO}	Input or Output Voltages		-0.3 to 6	V
V _{PP}	Program Supply		-0.3 to 26.5	V
P _D	Power Dissipation		1.5	W

Note: Except for the rating "Operating Temperature Range", stresses above those listed in the Table "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the SGS-THOMSON SURE Program and other relevant quality documents.

Figure 2. DIP Pin Connections



DEVICE OPERATION

The M2716 has 3 modes of operation in the normal system environment. These are shown in Table 3.

Read Mode. The M2716 read operation requires that $\overline{G} = V_{IL}$, $\overline{E}P = V_{IL}$ and that addresses A0-A10 have been stabilized. Valid data will appear on the output pins after time t_{AVQV} , t_{GLQV} or t_{ELQV} (see Switching Time Waveforms) depending on which is limiting.

Deselect Mode. The M2716 is deselected by making $\overline{G} = V_{IH}$. This mode is independent of $\overline{E}P$ and the condition of the addresses. The outputs are Hi-Z when $\overline{G} = V_{IH}$. This allows tied-OR of 2 or more M2716's for memory expansion.

Standby Mode (Power Down). The M2716 may be powered down to the standby mode by making $\overline{EP} = V_{IH}$. This is independent of \overline{G} and automatically puts the outputs in the Hi-Z state. The power is reduced to 25% (132 mW max) of the normal operating power. V_{CC} and V_{PP} must be maintained at 5V. Access time at power up remains either t_{AVQV} or t_{ELQV} (see Switching Time Waveforms).

Programming

The M2716 is shipped from SGS-THOMSON completely erased. All bits will be at "1" level (output high) in this initial state and after any full erasure. Table 3 shows the 3 programming modes.

Program Mode. The M2716 is programmed by introducing "0"s into the desired locations. This is done 8 bits (a byte) at a time. Any individual address, sequential addresses, or addresses chosen at random may be programmed. Any or all of the 8 bits associated with an address location may be programmed with a single program pulse applied to the EP pin. All input voltage levels including the program pulse on chip enable are TTL compatible.

The programming sequence is: with V_{PP} = 25V, V_{CC} = 5V, \overline{G} = V_{IH} and $\overline{E}P$ = V_{IL}, an address is selected and the desired data word is applied to the output pins (V_{IL} = "0" and V_{IH} = "1" for both address and data). After the address and data signals are stable the program pin is pulsed from V_{IL} to V_{IH} with a

2/9



M2716

DEVICE OPERATION (cont'd)

pulse width between 45ms and 55ms. Multiple pulses are not needed but will not cause device damage. No pins should be left open. A high level (V_{IH} or higher) must not be maintained longer than t_{PHPL} (max) on the program pin during programming. M2716's may be programmed in parallel in this mode.

Program Verify Mode. The programming of the M2716 may be verified either one byte at a time during the programming (as shown in Figure 6) or by reading all of the bytes out at the end of the programming sequence. This can be done with VPP = 25V or 5V in either case. VPP must be at 5V for all operating modes and can be maintained at 25V for all programming modes.

Program Inhibit Mode. The program inhibit mode allows several M2716's to be programmed simultaneously with different data for each one by controlling which ones receive the program pulse. All similar inputs of the M2716 may be paralleled. Pulsing the program pin (from V_{IL} to V_{IH}) will program a unit while inhibiting the program pulse to a unit will keep it from being programmed and keeping $\overline{G} = V_{IH}$ will put its outputs in the Hi-Z state.

ERASURE OPERATION

The M2716 is erased by exposure to high intensity ultraviolet light through the transparent window. This exposure discharges the floating gate to its initial state through induced photo current. It is recommended that the M2716 be kept out of direct sunlight. The UV content of sunlight may cause a partial erasure of some bits in a relatively short period of time.

An ultraviolet source of 2537 Å yielding a total integrated dosage of 15 watt-seconds/cm² power rating is used. The M2716 to be erased should be placed 1 inch away from the lamp and no filters should be used.

An erasure system should be calibrated periodically. The erasure time is increased by the square of the distance (if the distance is doubled the erasure time goes up by a factor of 4). Lamps lose intensity as they age, it is therefore important to periodically check that the UV system is in good order.

This will ensure that the EPROMs are being completely erased. Incomplete erasure will cause symptoms that can be misleading. Programmers, components, and system designs have been erroneously suspected when incomplete erasure was the basic problem.

Table 3. Operating Modes

Mode	ĒР	G	V_{PP}	Q0 - Q7		
Read	V _{IL}	V _{IL}	Vcc	Data Out		
Program	V _{IH} Pulse	V_{IH}	V_{PP}	Data In		
Verify	V _{IL}	V _{IL}	V _{PP} or V _{CC}	Data Out		
Program Inhibit	V _{IL}	V _{IH}	V_{PP}	Hi-Z		
Deselect	X	V _{IH}	V _{CC}	Hi-Z		
Standby	V _{IH}	X	Vcc	Hi-Z		

Note: X = V_{IH} or V_{IL}.



Philips Semiconductors

Product specification

Presettable synchronous 4-bit binary up/down counter

74HC/HCT193

FEATURES

- Synchronous reversible 4-bit binary counting
- · Asynchronous parallel load
- Asynchronous reset
- · Expandable without external logic
- · Output capability: standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT193 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT193 are 4-bit synchronous binary up/down counters. Separate up/down clocks, CP_U and CP_D respectively, simplify operation. The outputs change state synchronously with the LOW-to-HIGH transition of either clock input. If the CP_U clock is pulsed while CP_D is held HIGH, the device will count up. If the CP_D clock is pulsed while CP_U is held HIGH, the device will count down. Only one clock input can be held HIGH at any time, or erroneous operation will result. The device can be cleared at any time by the asynchronous master reset input (MR); it may also be loaded in parallel by activating the asynchronous parallel load input (PL).

The "193" contains four master-slave JK flip-flops with the necessary steering logic to provide the asynchronous reset, load, and synchronous count up and count down functions

Each flip-flop contains JK feedback from slave to master, such that a LOW-to-HIGH transition on the CP_{D} input will decrease the count by one, while a similar transition on the CP_{U} input will advance the count by one.

One clock should be held HIGH while counting with the other, otherwise the circuit will either count by two's or not at all, depending on the state of the first flip-flop, which cannot toggle as long as either clock input is LOW. Applications requiring reversible operation must make the reversing decision while the activating clock is HIGH to avoid erroneous counts.

The terminal count up (\overline{TC}_U) and terminal count down (\overline{TC}_D) outputs are normally HIGH. When the circuit has reached the maximum count state of 15, the next HIGH-to-LOW transition of CP_U will cause \overline{TC}_U to go LOW.

 $\overline{\text{TC}}_{\text{U}}$ will stay LOW until CP_U goes HIGH again, duplicating the count up clock.

Likewise, the \overline{TC}_D output will go LOW when the circuit is in the zero state and the CP_D goes LOW. The terminal count outputs can be used as the clock input signals to the next higher order circuit in a multistage counter, since they duplicate the clock waveforms. Multistage counters will not be fully synchronous, since there is a slight delay time difference added for each stage that is added.

The counter may be preset by the asynchronous parallel load capability of the circuit. Information present on the parallel data inputs $(D_0 \ to \ D_3)$ is loaded into the counter and appears on the outputs $(Q_0 \ to \ Q_3)$ regardless of the conditions of the clock inputs when the parallel load (\overline{PL}) input is LOW. A HIGH level on the master reset (MR) input will disable the parallel load gates, override both clock inputs and set all outputs $(Q_0 \ to \ Q_3)$ LOW. If one of the clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that clock will be interpreted as a legitimate signal and will be counted.

December 1990

Philips Semiconductors Product specification

Presettable synchronous 4-bit binary up/down counter

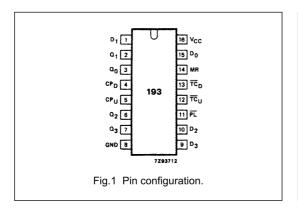
74HC/HCT193

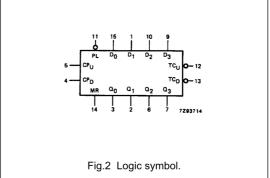
PIN DESCRIPTION

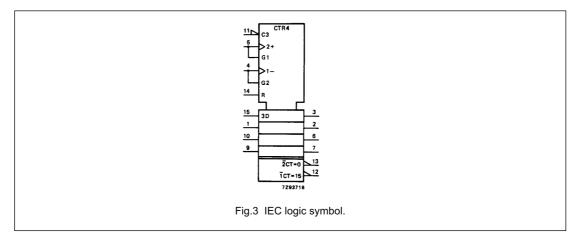
PIN NO.	SYMBOL	NAME AND FUNCTION
3, 2, 6, 7	Q ₀ to Q ₃	flip-flop outputs
4	CPD	count down clock input ⁽¹⁾
5	CPu	count up clock input ⁽¹⁾
8	GND	ground (0 V)
11	PL	asynchronous parallel load input (active LOW)
12	TC _U	terminal count up (carry) output (active LOW)
13	TC _D	terminal count down (borrow) output (active LOW)
14	MR	asynchronous master reset input (active HIGH)
15, 1, 10, 9	D ₀ to D ₃	data inputs
16	V _{CC}	positive supply voltage

Note

1. LOW-to-HIGH, edge triggered







December 1990 2

Philips Semiconductors Product specification

Presettable synchronous 4-bit binary up/down counter

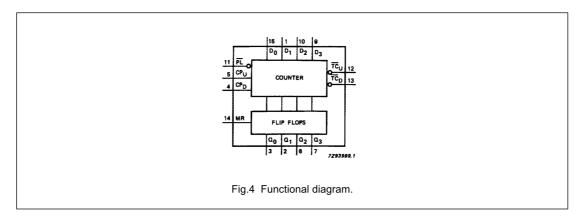
74HC/HCT193

FUNCTION TABLE

OPERATING MODE				INPU	ΓS						OUTF	i		
OPERATING WIODE	MR	PL	СР	CPD	D ₀	D ₁	D ₂	D ₃	Q_0	Q ₁	Q ₂	Q_3	TCu	TCD
reset (clear)	Н	Х	Х	L	Х	Х	Х	Х	L	L	L	L	Н	L
reset (clear)	Н	X	X	Н	Х	Х	X	X	L	L	L	L	Н	Н
	L	L	Х	L	L	L	L	L	L	L	L	L	Н	L
parallel load	L	L	Х	Н	L	L	L	L	L	L	L	L	Н	Н
	L	L	L	X	H	Н	Н	H	Н	Н	L L L H H t up	Н	L	Н
	L	L	Н	X	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
count up	L	Н	1	Н	Х	Х	Х	Х		count	up		H ⁽²⁾	Н
count down	L	Н	Н	1	Х	Х	Х	Х		ount o	down	L H H H H		H ⁽³⁾

Notes

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - X = don't care
 - ↑ = LOW-to-HIGH clock transition
- 2. $\overline{TC}_U = CP_U$ at terminal count up (HHHH)
- 3. $\overline{TC}_D = CP_D$ at terminal count down (LLLL)

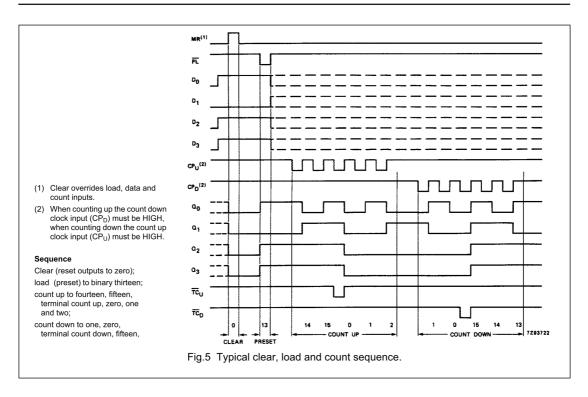


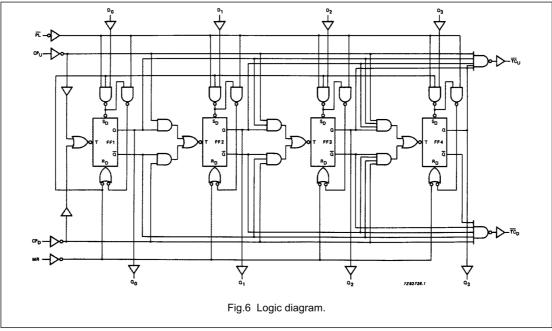
December 1990

Philips Semiconductors Product specification

Presettable synchronous 4-bit binary up/down counter

74HC/HCT193





December 1990 4



October 1987 Revised May 2002

MM74C150 • MM82C19 16-Line to 1-Line Multiplexer 3-STATE • 16-Line to 1-Line Multiplexer

General Description

The MM74C150 and MM82C19 multiplex 16 digital lines to 1 output. A 4-bit address code determines the particular 1-of-16 inputs which is routed to the output. The data is inverted from input to output.

A strobe override places the output of MM74C150 in the logical "1" state and the output of MM82C19 in the high-impedance state.

All inputs are protected from damage due to static discharge by diode clamps to V_{CC} and GND.

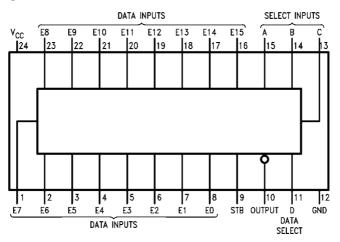
Features

- Wide supply voltage range: 3.0V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45 V_{CC} (typ.)
- TTL compatibility: Drive 1 TTL Load

Ordering Code:

Order Number	Package Number	Package Description
MM74C150N	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide
MM82C19N	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide

Connection Diagram



© 2002 Fairchild Semiconductor Corporation

DS005891

www.fairchildsemi.com

MM74C150 • MM82C19

Truth Table

MM74C150

Inputs																					Output
D	С	В	Α	STROBE	E0	E1	E2	E3	E4	E 5	E 6	E 7	E8	E 9	E10	E11	E12	E13	E14	E15	w
Х	Χ	Х	Х	1	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Х	Х	Х	Х	Χ	Х	1 (Note 1)
0	0	0	0	0	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	X	X	X	Χ	1
0	0	0	0	0	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	X	Χ	Χ	0
0	0	0	1	0	Х	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	Χ	Χ	Χ	1
0	0	0	1	0	Х	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
0	0	1	0	0	Х	Χ	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Х	Χ	1
0	0	1	0	0	Х	Χ	1	Χ	X	Χ	Χ	Χ	X	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
0	0	1	1	0	Х	Χ	Χ	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Х	Χ	1
0	0	1	1	0	Х	Χ	X	1	X	X	Χ	Χ	X	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
0	1	0	0	0	Х	Χ	Χ	Χ	0	X	Χ	Χ	X	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1
0	1	0	0	0	Х	Χ	Χ	Χ	1	Χ	Χ	Χ	Χ	Χ	Χ	Х	Χ	X	X	Χ	0
0	1	0	1	0	Х	Χ	X	Χ	X	0	Χ	Χ	X	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1
0	1	0	1	0	Х	Χ	Χ	Χ	Χ	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
0	1	1	0	0	Х	Χ	Χ	Χ	Χ	Χ	0	Χ	Χ	Χ	Χ	Х	Χ	Χ	Х	Χ	1
0	1	1	0	0	Х	Χ	Χ	Χ	Χ	Χ	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
0	1	1	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1
0	1	1	1	0	Х	Χ	Χ	Χ	X	X	Χ	1	X	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
1	0	0	0	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	Χ	Χ	X	Χ	X	X	Χ	1
1	0	0	0	0	Х	Χ	X	Χ	X	X	Χ	Χ	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0
1	0	0	1	0	Х	Χ	X	Χ	X	X	Χ	Χ	X	0	Χ	Χ	Χ	Χ	Χ	Χ	1
1	0	0	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1	Χ	Χ	Χ	X	X	Χ	0
1	0	1	0	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	Χ	Χ	Χ	Χ	Χ	1
1	0	1	0	0	Х	Χ	X	Χ	X	X	Χ	Χ	X	Χ	1	Χ	Χ	Χ	Χ	Χ	0
1	0	1	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	Χ	X	Χ	Χ	1
1	0	1	1	0	Х	Χ	X	Χ	X	X	Χ	Χ	X	Χ	Χ	1	Χ	Χ	Χ	Χ	0
1	1	0	0	0	Х	Χ	X	Χ	X	X	Χ	Χ	X	Χ	Χ	Χ	0	Χ	Χ	Χ	1
1	1	0	0	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1	Χ	Χ	Χ	0
1	1	0	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	0	Χ	Х	1
1	1	0	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	Χ	1	Χ	Χ	0
1	1	1	0	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	0	Χ	1
1	1	1	0	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	1	Х	0
1	1	1	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	Χ	Χ	Χ	0	1
1	1	1	1	0	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Х	Χ	Χ	Χ	Χ	1	0

Note 1: For MM72C19/MM82C19 this would be Hi-Z, everything else is the same.

www.fairchildsemi.com